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Correction: *In situ* formation of CsPbBr₃/ZnO bulk heterojunctions towards photodetectors with ultrahigh responsivity

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Correction for '*In situ* formation of CsPbBr₃/ZnO bulk heterojunctions towards photodetectors with ultrahigh responsivity' by Yalong Shen et al., *J. Mater. Chem. C*, 2018, DOI: 10.1039/c8tc04374d.

The authors regret an error in Fig. 2b of the original manuscript. The correct version of Fig. 2 is below.

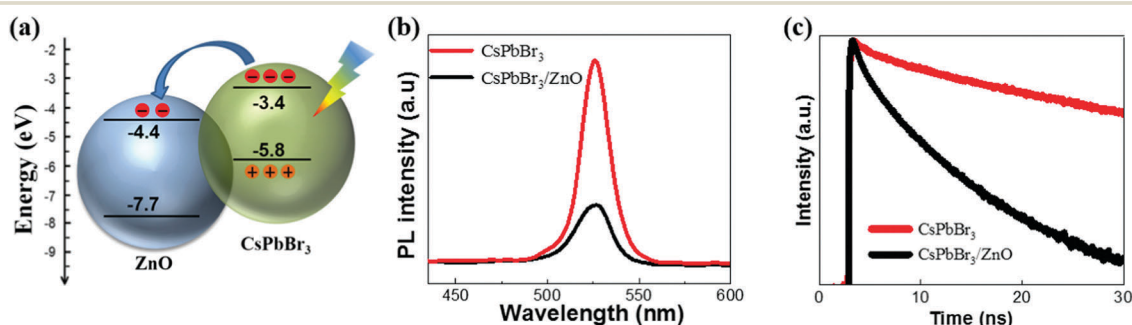


Fig. 2 (a) Band energy alignment between ZnO and CsPbBr₃. (b) PL spectra and (c) time-resolved PL decay curves of the pure CsPbBr₃ and CsPbBr₃/ZnO hybrid film.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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